















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

Product Specification

Domestic Part Number	SI2302B
Overseas Part Number	SI2302B
▶ Equivalent Part Number	SI2302B

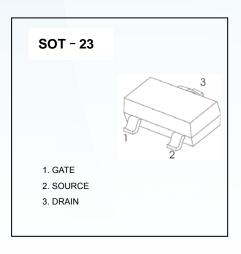




SOT-23 Plastic-Encapsulate MOSFETS

SI2302B N-Channel 20-V(D-S) MOSFET

V _{(BR)DSS}	R _{DS(on)} MAX	I _D
20 V	80mΩ@4.5V	
	100mΩ@2.5V	2.5A



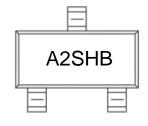
FEATURE

TrenchFET Power MOSFET

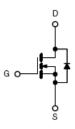
APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

MARKING



Equivalent Circuit



Maximum ratings (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage	V_{GS}	±8	V	
Continuous Drain Current	I _D	2.5	۸	
Continuous Source-Drain Current(Diode Conduction)	Is	0.6	A	
Power Dissipation	P_D	0.4	W	
Thermal Resistance from Junction to Ambient (t≤5s)	$R_{\theta JA}$	312.5	°C/W	
Operating Junction	TJ	150	°C	
Storage Temperature	T _{STG}	-55 ~+150	C	



T_a =25 $^{\circ}$ C unless otherwise specified

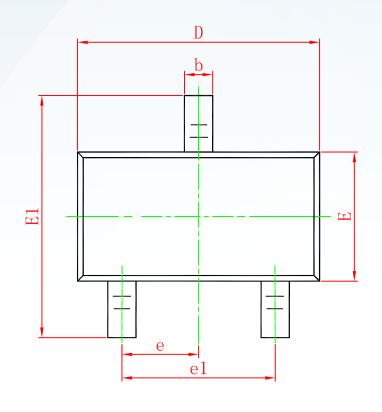
Parameter	Symbol	Test Condition	Min	Тур	Max	Units	
Static						l	
Drain-source breakdown voltage	V _{(BR)DSS}	V _G S = 0V, I _D =10μA	20			V	
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50µA	0.65	0.95	1.2	V	
Gate-body leakage	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			±100	nA	
Zero gate voltage drain current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA	
Drain-source on-resistance ^a	FD O()	Vgs =4.5V, ID =2.6A		0.045	0.070	Ω	
	rDS(on)	Vgs =2.5V, I _D =2.1A		0.060	0.100		
Forward transconductance ^a	g fs	V _{DS} =5V, I _D =3.6A		8		S	
Diode forward voltage	V _{SD}	I _S =0.94A,V _{GS} =0V		0.76	1.2	V	
Dynamic							
Total gate charge	Q_g			4.0	10		
Gate-source charge	Q_{gs}	V _{DS} =10V,V _{GS} =4.5V,I _D =3.6A		0.65		nC	
Gate-drain charge	Q_{gd}			1.5		-	
Input capacitance b	C _{iss}			300			
Output capacitance ^b	Coss	V _{DS} =10V,V _{GS} =0V,f=1MHz		120		pF	
Reverse transfer capacitance ^b	C _{rss}			80]	
Switching ^b							
Turn-on delay time	t _{d(on)}	\/ -10\/		7	15		
Rise time	tr	V _{DD} =10V,		55	80	ns	
Turn-off delay time	td(off)	R _L =5.5Ω, I _D ≈3.6A, V _{GEN} =4.5V,Rg=6Ω		16	60	- IIS	
Fall time	tf	V GEN - 7.0 V ,1 \9 - 012		10	25		

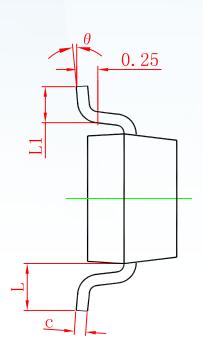
Notes:

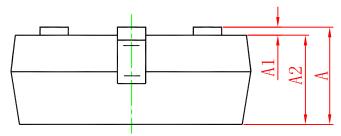
- a. Pulse Test : Pulse width≤300µs, duty cycle ≤2%.
- b. These parameters have no way to verify.



SOT-23 PACKAGE OUTLINE DIMENSIONS







Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	TYP.	0.037	TYP.	
e1	1.800	2.000	0.071	0.079	
L	0.550	0.550 REF.		REF.	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	



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